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## **Final Performance Report**

## First-principles Theory and Calculations of Electronic g-tensor Elements for Paramagnetic Defects in

Semiconductors and Insulators

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Geometries, Vertical Excitation Energies, Hyper fine Coupling Constants and Electronic g-tensor Elements for

Small Gallium Arsenide Clusters,  $Ga_x As_y (x + y = 3, 5)$ 

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#### Abstract

The g-tensors ( $2^{nd}$  order) of doublet radical gallium arsenide clusters  $Ga_xAs_y$  (x + y = 3, 5), were calculated from first principles using new packages. Geometry optimizations and hyperfine coupling constants are also reported, using the B3LYP/6-311+g(2df) level. ESR results were compared to experimental  $Ga_2As_3$  data, and previous calculations for  $Ga_2As_3$ ,  $GaAs_2$ ,  $Ga_2As_3$ . New ESR and structural results are presented for  $GaAs_4$  and  $Ga_4As$ . Our results for  $Ga_2As_3$ , the only Ga-As cluster for which experimental ESR data exist, were a better fit to experimental values than previous calculations, implying our  $\Delta g$  results for the other  $Ga_xAs_y$  clusters are also of good quality.

## 1. Introduction

To date there have been few experimental ESR studies on III-V doublet radicals, namely only on BNB<sup>1</sup> and  $Ga_2As_3^2$  to our knowledge. For triplet or quartet III-V radicals, experimental ESR data have only been fround for  $GaAs^+$  ( $X^4\Sigma^-$ ),  $^3GaP^+$  ( $X^4\Sigma^-$ ),  $^4GaAs^-Al_xGa_{1-x}As_5^-$  antisite defects ( $P_{Ga}$  in  $GaP_a^-$ ),  $^4GaAs_a^-$  and  $^4P_{In}$  in  $^4P_{In}$  in  $^4P_{In}$ ), and  $^4Ga^-$  are electron-irradiated  $^4GaP_a^-$ .

However there have been a number of theoretical studies on the electronic states and structures of III-V radicals, in particular for Ga-As containing neutral and ionic doublet radicals. <sup>10-22</sup> Arratia-Pérez and Hernández-Acevedo <sup>12</sup> calculated the magnetic Zeeman and hyperfine interactions of Ga<sub>2</sub>As<sub>3</sub> using the self-consistent Dirac scattered wave method (SCF-DSW-Xα) of Yang *et al*<sup>23</sup> and a first-order perturbation procedure, which confirmed Weltner's ESR spectral determination of a trigonal bipyramidal structure for Ga<sub>2</sub>As<sub>3</sub>: Arratia-Pérez and Hernández-Acevedo have also calculated the magnetic Zeeman and hyperfine interactions for GaAs<sub>2</sub> and Ga<sub>2</sub>As, <sup>13</sup> although to date there are no experimental ESR data for these species.

We compare these calculated and experimental data to our results, and also use the g-tensor results as a launching point to the study of larger clusters which approach bulk properties, with and without site defects.

## 2. Methods

GAUSSIAN 98 suite of programs<sup>24</sup> at the B3LYP/6-311+G(2df) level. Starting geometries were those given in the literature for GaAs<sub>2</sub>,<sup>14,17</sup> Ga<sub>2</sub>As,<sup>17,19</sup> Ga<sub>2</sub>As<sub>3</sub> and Ga<sub>3</sub>As<sub>2</sub>,<sup>19,25</sup> GaAs<sub>4</sub> and Ga<sub>4</sub>As,<sup>15</sup> with other possible geometries also examined. For GaAs<sub>4</sub> and Ga<sub>4</sub>As, only sketches of the structures were provided.<sup>15</sup>

The theoretical evaluation of g-tensors using perturbation theory is described in detail in refs. 26 and 27. The total  $\Delta g$  for a given molecule is comprised of first- and second-order terms. In this paper, only second-order g-tensor components were calculated, as the first-order contributions to the total  $\Delta g$  are expected to be

very small (ca. 100 ppm) in relation to the second order  $\Delta g$  values. The contribution to  $\Delta g$  (2<sup>nd</sup>) is due to the coupling of an excited state with the ground state, and is proportional to their spin-orbit coupling (SO) and magnetic transition moment (L) matrix elements, and inversely proportional to their energy separation ( $\Delta E$ ). The total second-order  $\Delta g$  is calculated as a sum-over-states expansion, which generally involves strong coupling to only the first few low-lying excited states.<sup>28-30</sup>

Programs developed earlier in this group<sup>27</sup> worked very well for 1<sup>31</sup> and 2<sup>nd</sup> order g-tensor calculations (e.g. refs. 27 - 30) but were limited to systems with up to ca. 80 electrons. Ga-As containing clusters, the focus of this paper, quickly surpassed this limitation. Also, speed is an issue if the calculation of larger clusters is to be practical. New programs were acquired and modified for our purposes to calculate the g-tensors of these Ga-As clusters. They are based on: the Turbomole package<sup>31</sup> for efficient integral and SCF calculations; on the Grimme multireference CI (MR CI) package,<sup>32</sup> which also gives the angular momentum (L) matrix elements that we require; and finally on the Marian-Hess mean-field spin-orbit integrals<sup>33</sup> as implemented by Schimmelpfennig,<sup>34</sup> and adapted for the Grimme MRCI package by Marian and Kleinschmidt.<sup>35</sup> Here the one-and two-electron spin-orbit elements are calculated from an effective one-electron one-center mean-field approximation. Therefore the spin-orbit matrix elements, which in full ab initio mode require large amounts of computer time, can be calculated in much less time but are not as accurate.

The electronic charge centroid (ECC) was taken as gauge origin. 36

Test results with the new package gave g-shifts within 15 - 20 % of MRCI<sup>37</sup> values for small molecules containing first- and second-row atoms (e.g. AlO, H<sub>2</sub>CO<sup>+</sup>; LiC<sub>2</sub>). <sup>38</sup> With the new package, the following III-V doublet radicals were studied: GaAs<sub>2</sub> (97 electrons), Ga<sub>2</sub>As (95 e), Ga<sub>2</sub>As<sub>3</sub> (161 e), Ga<sub>3</sub>As<sub>2</sub> (159 e), GaAs<sub>4</sub> (163 e), and Ga<sub>4</sub>As (157 e).

## 3. Optimized geometries

All geometry optimizations were done at the B3LYP/6-311+g(2df) level of theory. The results for the lowest energy structures are given in Table 1, and compared with those of previous calculations. The various structures are shown in Figure 1.

## 3.1. GaAs,

GaAs<sub>2</sub> was first examined in 1987,<sup>20</sup> and again in 2000<sup>17</sup> by Balasubramanian as a triangular  $C_{2v}$  structure; a 1991 study also considered a linear  $C_{\infty v}$  geometry.<sup>16</sup> Work by Meier *et al* in 1991<sup>14</sup> examined triangular  $C_{2v}$  and linear  $(D_{\infty h}, C_{\infty v})$  geometries. In all cases, the ground state was  $^2B_2$  with a  $C_{2v}$  triangular geometry.

## 3.2. Ga, As

For Ga<sub>2</sub>As. Balasubramanian reported an  $X^2B_2$  ground state with  $C_{2v}$  symmetry and an angle of 79.9°, with a  $C_1$  ( $^2A'$ ) structure (Ga-As = 2.283, 2.534 Å; Ga-As-Ga = 90.3°) 0.025 eV higher in energy (MRCI+Q, where Q was defined as multireference Davidson corrections to the MRCI energies for uncoupled quadruple clusters). Two other low lying states,  $^2B_1$  (2.52 Å, 108.2°,  $\Delta E = +0.22$  eV) and  $^2A_1$  (2.47 Å, 118.5°,  $\Delta E = +0.19$  eV), were also reported in ref.17. Balasubramanian found a  $^2B_1$  ground state in his 1991 study. In

Our attempts to reproduce Balasubramanian's  $C_{2v}$  ( $X^2B_2$ ) geometry from ref. 17 (2000) resulted instead in an Ga-As-Ga angle of ca. 96 degrees [for the 6-311-g(2df) basis set, B3 LYP gave Ga-As 2.384 Å,

96.3°; MPW1PW91 gave 2.358 Å, 93.3°; and MP2 gave 2.365 Å, 103.5°] for  $Ga_2As$ , inclose agreement with the local spin density (LSD) result of 98.0° from ref. 19 (see Table 1). Our linear  $D_{\omega h}$  ( $X^2\Pi_u$ , 2.447 Å) and  $C_{\omega v}$  ( $X^2\Pi_v$ , As-Ga = 2.246 Å, Ga-Ga = 2.665 Å) structures were 0.09 and 0.84 eV higher in energy, respectively, than our  $X^2B_2$   $C_{2v}$  bent geometry. In Bala subrama nian's 1991 paper with the  $^2B_1$  ground state,  $^{16}$  the ordering was  $C_{2v}$  ( $X^2B_1$ : 2.527 Å, 109.5°) 0 eV;  $D_{\omega h}$  (2.498 Å) +0.12 eV;  $C_{\omega v}$  (As-Ga = 2.319 Å, Ga-Ga = 2.735 Å) +0.68 eV.

## 3.3. Ga As,

The structure of Ga<sub>2</sub>As<sub>3</sub> was predicted in 1992 to be a D<sub>3h</sub> trigonal bipyramid with an X<sup>2</sup>A<sub>2</sub>" ground state, using the LSD method.<sup>19</sup> The ESR spectrum was obtained one year later, from which a trigonal bipyramidal structure was proposed.<sup>2</sup> MRCI calculations by Liao *et al*;<sup>25</sup> and HF followed by MP2 calculations by Piquini *et al*,<sup>15</sup> also resulted in D<sub>3h</sub> trigonal bipyramidal structures.

Our calculations showed the lowest energy structure of  $Ga_2As_3$  to have an  $X^2A_2$ " ground state with  $D_{3h}$  trigonal bipyramidal geometry, in agreement with the structure proposed from the experimental ESR data<sup>2</sup> and previous calculations. <sup>15,19,25</sup> Alternate possible geometries considered by us, shown in Figure 1, were: a  $C_{2v}$  square pyramid ( $X^2B_1$ ), 0.97 eV higher than the  $D_{3h}$  structure; and a  $C_s$  square pyramid ( $X^2A^2$ , two Ga in the 'base') 0.46 eV higher in energy.

## 3.4. Ga.As.

CASSCF and MRCI calculations by Liao *et al*,<sup>25</sup> using relativistic effective core potentials (RECP), showed two nearly degenerate isomers for  $Ga_3As_2$ : a distorted  $C_{2v}$  trigonal bipyramid ( $X^2A_1$ ,  $C_{2v}$  (a) in Figure 1), and a  $C_2$ , edge capped tetrahedron ( $X^2B_1$ ,  $C_2$ , (b) in Figure 1), with the  $C_{2v}$  trigonal bipyramid being lower in energy by 0.005 eV (MRCI+Q, and 0.03 eV CASSCF). LSD calculations by Lou *et al* gave similar results, with an energy separation of 0.01 eV.<sup>19</sup>

For  $Ga_3As_2$ , we also found that the lowest energy geometry was not  $D_{3h}$  as for  $Ga_2As_3$ , but rather a  $C_{2v}$  distorted trigonal bipyramid having a  $^2A_1$  ground state with the equatorial Ga atoms arranged in an isosceles triangle; the energy gap between the  $C_{2v}$  and  $D_{3h}$  geometries was 0.13 eV (0.1 eV in ref. 19). Other geometries we investigated (see Figure 1) were a  $C_{2v}$  edge-capped tetrahedron [ $X^2B_1$ ,  $C_{2v}$  (b) in Figure 1] 0.16 eV higher in energy; a  $C_3$  square pyramid ( $X^2A^2$ , two As in the 'base') 0.64 eV higher in energy; and a  $C_{2v}$  square pyramid [ $X^2A_1$ ,  $X^2$ ,  $X^$ 

## 3.5. GaAs

GaAs, was included in a study of electronic and structural trends in small GaAs clusters by Piquini et al, who carried out Hartree-Fock SCF calculations including all electrons and no symmetry constraints during optimization, followed by single-point MP2 calculations on the minimum energy configurations. <sup>15</sup> However, they did not report any geometry details other than a sketch of the molecule, the symmetry, and a table of selected bond orders.

Our results gave a  $C_{2v}$  edge-capped tetrahedron [ $X^2B_2$ ,  $C_{2v}$  (a) in Figure 1] as the lowest energy structure, resembling that shown in ref. 15. We calculated  $C_{4v}$  square pyramidal ( $X^2A_1$ ) and  $C_{2v}$  planar trapezoidal [ $X^2B_1$ ,  $C_{2v}$  (b) in Figure 1] geometries to be 0.30 and 1.68 eV, respectively, higher in energy than the  $C_{2v}$  edge-capped tetrahedron.

## 3.6. Ga\_As

Ga<sub>4</sub>As was also included in the study by Piquini *et al*,<sup>15</sup> and again no detailed geometrical information was given. The lowest energy structure we obtained for Ga<sub>2</sub>As was a  $C_2$ , planar trapezoidal structure  $(X^2A_1)$ , with the As atom in the center  $[C_2, (a)]$  in Figure 1], similar to the structure obtained by Piquini *et al*.<sup>15</sup> Our results showed square pyramidal  $(C_{4v}, X^2B_1)$ , and  $C_{2v}$  edge-capped tetrahedral  $[X^2A_2, C_{2v}]$  (b) in Figure 1] geometries to be respectively 0.23 and 0.56 eV higher in energy than the planar trapezoidal structure.

## 4. Hyperfine coupling constants

The atomic charges, spin densities (SD) and hfcc data are given in Table 2. For all six molecules, the Ga atoms carry positive charges and all As atoms are negatively charged, as expected since As is more electronegative than Ga. The SOMOs are shown in Figure 2.

#### 4.1. GaAs,

The SOMO of GaAs<sub>2</sub> is composed of an in-phase combination of a Ga p<sub>y</sub> orbital with As p<sub>z</sub> orbitals, forming σ-type antibonding orbitals along each Ga-As bond, as also reported in ref. 13. These Ga-As antibonding orbitals of the SOMO are ca. parallel to the z-axis, perhaps due to the small As-As distance (2.193 Å) which is slightly shorter than that calculated for As; (2.30 Å) and As<sub>2</sub> (2.31 Å).<sup>14</sup>

The SD is greater on the As atoms (0.368 per atom) than on the Ga atom (0.262). This is in good agreement with the spin populations calculated in ref. 13, who report 0.338 (0.106 isotropic, 0.232 a nisotropic) per Ga and 0.331 (0.121 isotropic, 0.210 a nisotropic) per As atom. The anisotropic spin-dipolar couplings  $(T_{xx,yy,zz}$  in Table 2) are much larger than  $A_{iso}$  for both Ga and As, and the relative magnitudes of our spin-dipolar couplings are similar to those from ref. 13 (see Table 2).

## 4.2. Ga As

The SOMO is formed from an in-phase combination of a  $p_x$  orbital from all three atoms according to ref. 13, but this corresponds to the SOMO-1 in our calculations: our SOMO is comprised of three in-plane p-orbitals:  $p_z$  on As and the  $p_\alpha$  orbitals of Ga lie along the As-Ga bonds such that the negative lobes for all three orbitals point toward the center of the molecule. Our geometry differs slightly from that used in ref. 13; this could be the cause of the different SOMOs, and would also affect the g-tensor calculations (see below).

More than half of the SD in Ga<sub>2</sub>As resides on the As (0.515), with 0.242 per Ga atom. A similar trend is reported in ref. 13, but with more SD on the apical As atom: 0.694 per As and 0.153 per Ga, with larger

anisotropic than isotropic SD contributions for each atom  $A_{iso}$  is largest for the Ga atoms, and the spin-dipole couplings  $(T_{xx,yy,zz})$  are smaller for Ga than As, similar to the results from ref. 13.

## 4.3. Ga, As;

Our results place the majority of the SD on the Ga atoms (0.369), with only 0.088 per As atom. This agrees with the SD distribution from ref. 12 (0.314 per Ga, 0.124 per As). Based on the experimental results it was estimated that the unpaired electron was mainly confined to  $p\sigma$  orbitals on the axial gallium atoms. This estimation is not supported by the SOMO (as also noted in ref. 12), which shows sizeable in-phase  $\pi$ -bonding between the equatorial As atoms via p, orbitals, and  $p_{\sigma}$  antibonding between Ga and As atoms.

Our  $A_{iso}$  differs from the experimental <sup>69</sup>Ga<sub>2</sub>As<sub>3</sub> (Ar matrix)<sup>2</sup> result by 13%. Ref. 12 reports calculated  $A_{iso}$  values for only <sup>74</sup>Ga, even though the natural abundance is 60.4% <sup>69</sup>Ga and 39.6% <sup>71</sup>Ga; their  $A_{iso}$  value is almost identical to the derived experimental <sup>71</sup>Ga<sub>2</sub>As<sub>3</sub> result. The experimental results were derived assuming  $g_{\parallel} = g_{e}$ , and  $A_{\parallel} \cong A_{\perp} \cong A_{iso}$  for As. This does not appear to be valid, based on results from ref. 12 where anisotropic spin distributions for the As atoms were calculated to be ca, twice the isotropic spin distribution.

## 4.4. Ga, As,

The small distortion from  $D_{3h}$  to  $C_{2v}$  symmetry makes a significant impact on the SD and charges of the Ga atoms in  $Ga_3As_2$ , as well as the SOMO. The SOMO is composed of in-phase  $p_v$  orbitals on  $Ga_1$  and the As atoms, with  $p_\sigma$  orbitals on  $Ga_2$  and  $Ga_3$  oriented to form  $Ga_2$ -As and  $Ga_3$ -As antibonds. The SD is four times larger, and the charge is two times smaller, for the  $Ga_1$  atom (Table 2) than for  $Ga_2$  and  $Ga_3$ . The  $A_{iso}$  for  $Ga_1$  is much larger than for  $Ga_2$  and  $Ga_3$ , and the SD, charge,  $A_{iso}$ , and anisotropic ( $T_{xx,yy,zz}$ ) higher values for  $Ga_1$  are all similar to that for each of the Ga atoms in  $Ga_2As_3$ .

The SOMO of GaAs<sub>4</sub> lies in the yz-plane from  $p_y$  orbitals on all atoms; the orbitals on Ga, As<sub>1</sub> and As<sub>2</sub> are in-phase, and of opposite phase to those on As<sub>3</sub> and As<sub>4</sub>.

The majority of SD lies on  $As_1$  and  $As_2$  (see Figure 1), with very little on the other three atoms. This is reflected in the larger  $A_{dip}$  values for these atoms (Table 2), which are an order of magnitude larger for  $As_1$  and  $As_2$  than for  $As_3$  and  $As_4$ .

## 4.6. Ga\_As

The SOMO lies in the plane of the molecule, with p<sub>y</sub> orbitals of Ga<sub>1</sub> and Ga<sub>2</sub> oriented to be bonding between Ga<sub>1</sub>-Ga<sub>2</sub>, with the pσ orbitals of Ga<sub>4</sub> and Ga<sub>5</sub> positioned to be Ga<sub>1</sub>-Ga<sub>5</sub> and Ga<sub>2</sub>-Ga<sub>4</sub> antibonding. The p<sub>z</sub> orbital on As is small and is oriented to be in phase with the p<sub>y</sub> orbitals between Ga<sub>1</sub> and Ga<sub>2</sub>.

There is almost no SD associated with the As atom in Ga<sub>4</sub>As, but the largest atomic charge resides on As (-0.509). Most of the SD resides on Ga<sub>1</sub> and Ga<sub>2</sub>, and is ca. twice the SD for Ga<sub>3</sub> and Ga<sub>4</sub>; whereas the charges on Ga<sub>1</sub> and Ga<sub>2</sub> is ca. half that for Ga<sub>3</sub> and Ga<sub>4</sub>. This inverse relationship between charge and SD was observed by Bruna and Grein for alkali-metal diatomic radical cations.<sup>30</sup>

## 5. G-tensors

In Table 3, the types of excited states that couple with four different ground states in  $C_{2v}$  symmetry  $(X^2A_1, X^2A_2, X^2B_1, X^2B_2)$  are listed. Table 4 summarizes our total  $\Delta g$  ( $2^{nd}$  order) values and compares them to known experimental and theoretical results. To our knowledge there are no experimental or calculated ESR data for  $Ga_3As_2$ ,  $GaAs_4$ , or  $Ga_4As$ . For all  $Ga_xAs_y$  doublet radicals (x + y = 3, 5)  $\Delta E$ , SO, L and  $\Delta g$  values for the first five excited states for each irreducible are given in Tables 5 - 10, and results for higher excited states if they have a strong magnetic coupling with the ground state. Fifteen excited states were calculated for  $Ga_3As_2$ ,  $GaAs_4$  and  $Ga_4As$  since significant magnetic coupling with the ground state was still observed in the higher states of initial 9-root calculations. Tables 5 - 10 can also be used for vertical excitation energies, which

are given in the body of the table or as a footnote.

All  $C_{2v}$  molecules have the z-axis along the  $C_2$  symmetry axis.  $GaAs_2$  and  $Ga_2As$  are placed in the yz-plane.

## 5.1. GaAs<sub>2</sub>

Table 5 shows that  $\Delta g_{xx}$  for GaAs<sub>2</sub> is governed by the coupling of  $1^2A_1$  ( $4a_1 \rightarrow 2b_2$ , SOMO-1 to SOMO) and  $2^2A_1$  ( $3a_1 \rightarrow 2b_2$ , SOMO-3 to SOMO) with  $X^2B_2$ .

The  $\Delta g_{yy}$  component is dominated by the coupling with  $1^2A_2$  ( $2b_2 - 2b_1$ ), SOMO to LUMO+1. There are also strong couplings with  $2^2A_2$  and  $3^2A_2$  but they almost cancel each other: their individual  $\Delta g_{yy}$  contributions are similar in magnitude and opposite in sign. This is a general trend observed for a pair of states generated by a three open shell configuration,  $^{28,39,40}$  e.g. for  $H_2CO^+$  the  $\Delta E$ , SO and L values for the  $1,2^2A_2$  states ( $\Delta g_{yy}$ ) were of similar magnitude but their contributions to  $\Delta g$  were of opposite sign.  $^{28}$  In the case of GaAs<sub>2</sub>, the  $\Delta E$  and SO values for  $2^2A_2$  and  $3^2A_2$  are similar, but the L values differ by ca. 50% (15% deviation in L values in the  $H_2CO^+$  example  $^{28}$ ). This variation of the L values may occur since although the leading configuration for both  $2^2A_2$  and  $3^2A_2$  is a  $4a_1 - 2b_1$  excitation (90% and 85%, respectively), there are small differences in the other configurations contributing to  $2^2A_2$  and  $3^2A_2$  (Table 5).

The total  $\Delta g_{xx}$  component is an order of magnitude smaller than  $\Delta g_{xx}$  and  $\Delta g_{yy}$ . Although the strongest couplings with  $X^2B_2$  arise from  $5^2B_1$  and  $6^2B_1$ , their  $\Delta g$  contributions almost cancel each other, since both of these states derive from a three open shell configuration<sup>28,39,40</sup> ( $3a_1 \rightarrow 1a_2$ , SOMO-3 to LUMO). In this case the  $\Delta E$  for the two states are very close, but the SO and L values differ by ca. 50%. These differences arise from mixing of the leading configuration.

Calculated g-shifts for GaAs<sub>2</sub> by Arratia-Perez *et al*<sup>13</sup> utilized a first-order perturbation procedure based on the SCF-DSW-X $\alpha$  method,<sup>23</sup> and a geometry by Lou *et al*.<sup>18,19</sup> Although three g-components are expected for C<sub>2</sub>, symmetry, they give only  $\Delta g_{\alpha}$  and  $\Delta g_{\perp}$  values. Assuming their  $\Delta g_{\beta}$  is along As-As ( $\Delta g_{yy}$ ) and

 $\Delta g \perp$  is  $\Delta g_{xx}$ , our calculated  $\Delta g$  values for GaAs<sub>2</sub> differ significantly from those calculated in ref. 13, being ca. 70000 ppm larger in magnitude. There is no experimental ESR data available for GaAs<sub>2</sub> to gauge the accuracy of either result.

## 5.2: Ga, As.

The  $\Delta g_{xx}$  value of  $Ga_2As$  is not dominated by coupling with any one excited state; rather  $1^2A_1 - 4^2A_1$  all make large negative contributions to  $\Delta g_{xx}$ , countered to a small extent by  $6^2A_1$  (Table 6).

The two largest contributions to  $\Delta g_{yy}$  are negative values from  $2^2A_2$  and  $4^2A_2$ , countered by a positive one from  $5^2A_2$ . As the leading configurations for  $4^2A_2$  and  $5^2A_2$  are the same  $(3a_1 - 2b_1)$ , the  $\Delta E$  and L values are similar and their  $\Delta g$  contributions are of opposite sign, but the SO values differ by ca. 50%. This is due to  $5^2A_2$  being dominated by a three open shell configuration  $(3a_1 - 2b_1)$ , whereas  $4^2A_2$  is more evenly comprised of this (40 %) and a double excitation from the SOMO-1 to the SOMO and LUMO+1  $(3a_1^2 - 2b_2^2)$  (37 %).

The  $\Delta g_{zz}$  value is dominated by coupling to  $1^2B_1$ , with contributions from 3,5,6 $^2B_1$ . The  $5^2B_1$  and  $6^2B_1$  states have the same leading three open shell configuration, SOMO-1 (3a<sub>1</sub>) to the LUMO+2 (1a<sub>2</sub>), but again the  $\Delta g$  contributions from these two states do not cancel <sup>28,39,40</sup> due to differences in the configuration setup.

As with GaAs<sub>2</sub>, only  $\Delta g_{\parallel}$  and  $\Delta g_{\perp}$  values for Ga<sub>2</sub>As are given in ref. 13. If we assume that their  $\Delta g_{\parallel}$  is along Ga-Ga (y-axis, as for GaAs<sub>2</sub> along As-As), then the  $\Delta g_{yy}$  comparison is very poor. If their  $\Delta g_{\parallel}$  corresponds instead to  $\Delta g_{yz}$ , then the result differs from ours by ca. 20%, but is inconsistent with the GaAs<sub>2</sub> x, y, z-axis assignments.

## 5.3. Ga<sub>2</sub>As<sub>3</sub>

In  $D_{3h}$  symmetry ( $X^2A_2$ "), the standard orientation places the Ga atoms of  $Ga_2As_3$  along the z-axis, with the As atoms in the xy-plane; x and y (and  $\Delta g_{xy}$  and  $\Delta g_{yy}$ ) are degenerate ( $^2E'$ ). Our  $\Delta g$  calculations were done

with  $Ga_2As_3$  in  $C_{2\nu}$  symmetry (X<sup>2</sup>B<sub>1</sub>), placing the Ga atoms along the x-axis and the As atoms in the yz-plane with one As atom lying on the z-axis. In this case, the  $^2A_1$  and  $^2B_2$  states correspond to  $^2E$ . For checking the accuracy of our calculations, we calculated  $\Delta g$  for both  $^2A_1$  and  $^2B_2$  states. The degenerate components of  $\Delta g$  will always be called  $\Delta g_{xx}$  and  $\Delta g_{yy}$ , corresponding to the  $D_{3h}$  notation. Due to the independent selection of reference configurations and extrapolation for  $^2A_1$  and  $^2B_2$  states, slightly different values were obtained for  $\Delta g_{xx}$  and  $\Delta g_{yy}$ .

The degree of degeneracy of  $\Delta g_{xx}$  and  $\Delta g_{yy}$  can be checked in Table 7. The values are dominated by coupling of the ground state with  $3^2A_1$  and  $2^2B_2$ , respectively, corresponding to excitation from the SOMO  $(3b_1)$  to the degenerate LUMO  $(6a_1)$  for  $\Delta g_{xx}$  and LUMO+1  $(3b_2)$  for  $\Delta g_{yy}$ . The second largest contribution is from  $5^2A_1$ , an excitation from the SOMO to the degenerate LUMO+4  $(7a_1)$ , and from  $4^2B_2$ , SOMO to LUMO+3  $(5b_2)$ . The remaining major excited state couplings involve 6,  $7^2A_1$  and 5,  $6^2B_2$ , excitations from the degenerate SOMO-2  $(1a_2, \Delta g_{xx})$  and SOMO-1  $(2b_1, \Delta g_{zz})$  to the LUMO+2  $(4b_2)$ , resulting in three open shell configurations. As shown in Table 7 for  $\Delta g_{yy}$ , the  $\Delta E$ , SO and L values for  $5^2B_2$  and  $6^2B_2$  are very similar and the  $\Delta g$  values are opposite in sign. This behaviour is expected for pairs of states generated by a three open shell configuration.  $^{28,39,40}$  This is not as evident in  $6^2A_1$  and  $7^2A_1$  in  $\Delta g_{xx}$ , where the SO and L values are similar, but the  $\Delta E$  values differ by 1.1 eV.

As shown in Table 7,  $\Delta g_{xx}$  was calculated to be an order of magnitude smaller than  $\Delta g_{yy}$  and  $\Delta g_{zz}$ , with the largest contribution from coupling with the  $3^2A_2$  state, an excitation from SOMO-5 ( $4a_1$ ) to LUMO+2 ( $4b_2$ ).

Ga<sub>2</sub>As<sub>3</sub> is the only Ga<sub>8</sub>As<sub>3</sub> doublet radical with published experimental ESR data; comparison of our results to the experimental<sup>2</sup> and published theoretical<sup>12</sup> g-tensor data is given in Table 4. Our results are in good agreement with experiment,<sup>2</sup> being a much closer fit than the theoretical results from ref. 12.

In our calculations the three Ga atoms of  $Ga_3As_2$  were placed in the yz-plane and the two As atoms along the x-axis. The distortion from a  $D_{3h}$  trigonal bipyramid to  $C_{2v}$  symmetry was accomplished by having the  $Ga_1-Ga_2$  (and  $Ga_1-Ga_3$ ) distance shorter than  $Ga_2-Ga_3$  [See Figure 1,  $C_{2v}$  (a)].  $Ga_1$  lies along the z-axis,  $Ga_2$  and  $Ga_3$  along y.

The  $\Delta g_{xx}$  value is governed by the coupling of  $1^2B_2$  and  $3^2B_2$  with the  $X^2A_1$  ground state (Table 8).

There are numerous contributions to  $\Delta g_{yy}$ , the largest being  $1^2B_1$  ( $2b_1 - 5a_1$ , SOMO-3 to SOMO) and  $3^2B_1$  ( $5a_1 - 3b_1$ , SOMO to LUMO+2), which almost cancel each other. The overall  $\Delta g_{yy}$  is relatively small, with most of the small negative contributions ( $2,4,6,14^2B_1$ ) being negated by positive contributions from  $5^2B_1$  and  $11^2B_1$ .

The overall  $\Delta g_{zz}$  is also small, due to cancelling contributions from pairs of states generated by three open shell configurations. Contributions to  $\Delta g_{zz}$  from  $2^2A_2$  and  $3^2A_2$ , both having the same configuration, almost cancel each other; their  $\Delta E$  values are almost identical, and although the SO of  $2^2A_2$  is ca. 70% larger than that of  $3^2A_2$ , the L value for  $2^2A_2$  is ca. 80% smaller than that of  $3^2A_2$ . The leading configuration for  $4^2A_2$  and  $5^2A_2$  is the same ( $1a_2 - 6a_1$ , SOMO-2 to LUMO+1), but the respective  $\Delta g$ 's differ vastly in magnitude, due probably to some mixing of configurations.

## 5.5. GaAs

The molecule was oriented such that Ga lies on the z-axis, and  $As_1$ - $As_2$  in the yz-plane;  $As_3$  and  $As_4$  lie in the xz-plane [Figure 1,  $C_{2y}$  (a)].

For  $\Delta g_{xx}$ , magnetic coupling was dominated by coupling with  $1^2A_1$  ( $3b_2 \rightarrow 6a_1$ , SOMO to LUMO). Large negative contributions from  $2.5^2A_1$  are effectively cancelled by  $4.9^2A_1$  (Table 9).

In contrast to  $\Delta g_{xx}$ , the overall  $\Delta g_{yy}$  and  $\Delta g_{zz}$  values were small due to cancelling positive and negative  $\Delta g$  components from numerous excited states. For  $\Delta g_{yy}$ , large contributions from  $1^2A_2$  and  $2^2A_2$  are of opposite (three open shells) and nearly cancel. The next largest contributions arise from  $5^2A_2$  and  $10^2A_3$ , both being

positive. However, the overall  $\Delta g_{yy}$  is relatively small and negative due to negative contributions from a number of states  $(3,4,6,7,9,11^2A_2)$ .

The largest contributions to  $\Delta g_{zz}$ , from  $1^2B_1$  and  $2^2B_1$ , are again of opposite sign although the two states do not derive from the same configuration. Next largest in magnitude are contributions from  $8^2B_1$  and  $11^2B_1$ , which have the same three open shell configuration. Due to other contributing states, the final  $\Delta g_{zz}$  is again relatively small.

## 5.6. Ga<sub>4</sub>As

In our calculations Ga<sub>4</sub>As was in the yz-plane, with the z-axis bisecting the Ga<sub>2</sub>-As-Ga<sub>3</sub> and Ga<sub>4</sub>-As-Ga<sub>5</sub> angles (see Figure 1); the x-axis was perpendicular to the molecular plane.

For  $\Delta g_{xx}$ , the magnetic coupling was dominated by two excited states  $(1,2^2B_2)$ , the leading configurations for which were the same  $(5a_1 \rightarrow 4b_2 \text{ and } 3b_2 \rightarrow 5a_1)$  but contributed in an approximately opposite manner  $(1^2B_2: 62\% \text{ and } 29\%; 2^2B_2: 29\% \text{ and } 63\%, \text{ respectively, see Table 10})$ .

The largest contributions to  $\Delta g_{yy}$  were from high-lying excited states  $(6,7,8^2B_1)$ . All of the states contributing significantly to  $\Delta g_{yy}$  had negative  $\Delta g$  components with the exception of  $5^2B_1$ , which is one of a pair of states (with  $6^2B_1$ ) from a three open shell configuration  $(4a_1 \rightarrow 2b_1)$ .

High-lying states also dominate  $\Delta g_{zz}$ , with the largest negative contributions from 6,7,12,14 $^2$ Å<sub>2</sub>. The largest positive  $\Delta g$  contribution is from  $11^2$ Å<sub>2</sub>, which has the same three open shell configuration as  $12^2$ Å<sub>2</sub> (3b<sub>2</sub>  $\rightarrow$  3b<sub>1</sub>), although neither state is dominated by this configuration (42% for  $11^2$ Å<sub>2</sub>, 60% for  $12^2$ Å<sub>2</sub>). The other state with a positive contribution to  $\Delta g_{zz}$  is  $4^2$ Å<sub>2</sub>, which has the same leading three open shell configuration as  $6^2$ Å<sub>2</sub> (3b<sub>2</sub>  $\rightarrow$  2b<sub>1</sub>); here the SO values are quite different and the  $\Delta E$ 's differ by ca. 1 eV, and two  $\Delta g$  contributions are opposite in sign but are not similar in magnitude.

#### 6. Summary and Conclusions

New programs developed for the calculation of g-tensors, based on multireference CI wavefunctions, have been capable of determing g-tensors for III-V doublet radicals with up to 163 electrons in an efficient manner, and without the need for RECPs (although this may still be necessary for the study of larger clusters).

In contrast to smaller molecules for which strong magnetic coupling with the ground state is observed with only a few excited states (e.g. refs. 28-30), significant contributions to  $\Delta g$  were often observed from various higher excited states of  $Ga_xAs_y$ . This is due in part to the higher energy-density of excited states of these molecules, e.g. 14 excited states are within 4 eV for  $Ga_xAs$  ( $\Delta g_{zz}$  in Table 10).

From comparison with experimental ESR data for  $Ga_2As_3^2$  (Table 4) it is evident that our new g-tensor results are significantly better than the DFT results reported in ref. 12, although they correctly reproduced the trends of the experimental results (i.e.  $\Delta g_{xx} \ll \Delta g_{yy}$ ,  $\Delta g_{zz}$ ). This suggests that our g-tensor results for  $GaAs_2$  and  $Ga_2As$  are also improved over published DFT values, <sup>13</sup> and that results for the other clusters are reliable. Future work includes using these new programs to investigate the structures and properties of larger III-V clusters (11+ atoms), and the study of paramagnetic defects (heteroatomic, <sup>5</sup> anti-site <sup>6-8</sup> and hole defects) within these larger clusters. Results presented in this paper show that one does not need to consider all valence electrons (VE), which decreases calculation times and may allow larger molecules to be calculated before the use of RECPs is required.

Also planned are modifications to the program code to allow g-tensor calculations for triplet and quartet multiplicities. A number of AB III-V compounds for which experimental ESR data are available (e.g. GaAs<sup>+</sup>, GaP<sup>+</sup>) have quartet ground states. Higher spin states are not restricted to ions, e.g. GaP<sub>3</sub> has a <sup>3</sup>A<sub>2</sub> ground state. These would be helpful in gauging the quality of our results, since to our knowledge Ga<sub>2</sub>As<sub>3</sub><sup>2</sup> and BNB<sup>1</sup> are the only III-V doublet radicals with published ESR data.

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Table 1. Optimized bond distances (Å) and angles (deg) from this work [B3LYP/6-311+G(2df)], and comparison to literature values, for all  $Ga_xAs_y$  (x + y = 3, 5) doublet radicals.

| Molecule, symmetry, ground state                    |             | Results                               |   |
|---|-------------|---------------------------------------|---|
| $GaAs_2  C_{2\nu}, X^2B_2$                          | This work   | Ref. 17 (MRCI)                        | Ref. 14 (MRCI)                          |
| Ga-As   | . 2.775     | 2.80                                  | 2.86                                    |
| As-Ga-As  | 46.5        | 45.9                                  | 46.6                                    |
|   |             | •                                     | ,                                       |
| $Ga_2As$ $C_{2v}$ , $X^2B_2$                        | This work . | Ref. 17 (MRCI)                        | Ref. 19 (LSD)                           |
| Ga-As   | 2.384       | 2.407                                 | 2.33                                    |
| Ga-As-Ga  | 96.3        | 79.9                                  | 98.0                                    |
| Same and the same                                   |             | · · · · · · · · · · · · · · · · · · · | • |
| $Ga_2As_3$ $D_{3h}$ , $X^2A_2$ "                    | . This work | Ref. 25 (MRCI)                        | Ref. 19 (LSD)                           |
| Ga-Ga   | 4.268       | not reported                          | not reported                            |
| Ga-As   | 2.594       | 2.589                                 | 2.65                                    |
| As-As   | 2.555       | 2.563                                 | 2.62                                    |
|   |             |                                       |   |
| $Ga_3As_2$ $C_{2v}$ , $X^2A_1$                      | This work   | Ref. 25 (MRCI)                        | Ref. 19 (LSD)                           |
| $Ga_1$ - $Ga_2$ , $Ga_1$ - $Ga_3$ <sup>a</sup>      | 3.751       | 3.702                                 | 3.72                                    |
| Ga <sub>2</sub> -Ga <sub>3</sub>                    | 3.979       | 4.114                                 | 4.57                                    |
| Ga <sub>1</sub> -As <sub>1</sub>                    | 2.446       | 2.401                                 | 2.41                                    |
| $Ga_2$ - $As_1$ , $Ga_3$ - $As_1$                   | 2.671       | 2.725                                 | 2.59.                                   |
| $As_1-As_2$   | 2.725       | 2.782                                 | 2.70                                    |
| $Ga_2$ - $Ga_1$ - $Ga_3$ .                          | 64.0        | ·67.5                                 | 70.0                                    |
| $As_1$ - $Ga_1$ - $As_2$                            | 67.7        | 70.8                                  | 67.9                                    |
| $As_1$ - $Ga_2$ - $As_2$ , $As_1$ - $Ga_3$ - $As_2$ | 61.3        | 61.4                                  | 55.2                                    |

## Table 1 continued.

| $GaAs_4  C_{2v}, X^2B_2$  | This work | Ref. 15                          |
|---|-----------|----------------------------------|
| Ga-As <sub>1</sub> , Ga-As <sub>2</sub> <sup>a</sup>  | 3.116     | no data given:                   |
| Ga-As <sub>3</sub> , Ga-As <sub>4</sub>   | 2.545     | C <sub>2v</sub> , edge-capp ed   |
| As <sub>1</sub> -As <sub>3</sub> , As <sub>1</sub> -As <sub>4</sub> , As <sub>2</sub> -As <sub>3</sub> , As <sub>2</sub> -As <sub>4</sub> | 2.454     | tetrahedron                      |
| As <sub>1</sub> -As <sub>2</sub>  | 3.006     |                                  |
|   |           |                                  |
| $Ga_4As$ $C_{2v}$ , $X^2A_1$  | This work | Ref. 15                          |
| Ga <sub>1</sub> -As, Ga <sub>2</sub> -As <sup>a</sup>   | 2.588     | no data given:                   |
| Ga <sub>3</sub> -As, Ga <sub>4</sub> -As  | 2.487     | C <sub>2v</sub> , planar         |
| Ga <sub>1</sub> -Ga <sub>3</sub> , Ga <sub>2</sub> -Ga <sub>4</sub>   | 2.870     | trapezoid                        |
| Ga <sub>1</sub> -Ga <sub>2</sub>  | 2.599     | with As in center                |
| Ga <sub>1</sub> -Ga <sub>4</sub> , Ga <sub>2</sub> -Ga <sub>3</sub>   | 4.583     | man and the second second second |
| Ga <sub>3</sub> -Ga <sub>4</sub>  | 4.913     |                                  |
| Ga <sub>1</sub> -As-Ga <sub>2</sub> · · · ·   | 60.3      |                                  |
| Ga <sub>1</sub> -As-Ga <sub>3</sub> , Ga <sub>2</sub> -As-Ga <sub>4</sub>   | 68.8      |                                  |
| Ga <sub>1</sub> -As-Ga <sub>4</sub> , Ga <sub>2</sub> -As-Ga <sub>3</sub>   | 129.1     |                                  |
| Ga <sub>3</sub> -As-Ga <sub>4</sub>   | 162.0     | •                                |

a See Figure 1 for atom labelling scheme.

Table 2. Spin densities, atomic charges, and hyperfine coupling constants (MHz) for all  $Ga_xAs_y$  (x + y = 3, 5) doublet radicals.

| Molecule  | Atom                              | Spin Density <sup>a</sup> | Charge <sup>a</sup> | $A_{iso}$ | $T_{xx} / T_{yy} / T_{zz}^{b}$ |
|---|-----------------------------------|---------------------------|---------------------|-----------|--------------------------------|
| GaAs <sub>2</sub> C <sub>2v</sub> , X <sup>2</sup> B <sub>2</sub> | Ga                                | 0.262                     | 0.226               |           | -57 / 131 / -74                |
| Ref. 10   | •                                 | 0.338                     | 0.193               |           | · 83 <sup>d</sup>              |
| •   | As                                | 0.368                     | -0.113              | · . 7     | · -111 / -113' / 225'          |
| Ref. 10   |                                   | 0.331                     | -0.096              |           | 125 <sup>d</sup>               |
| $Ga_2As$ $C_{2v}$ , $X^2B_2$                                      | Ga                                | 0.242                     | 0.128               | 447       | -63 / -81' / -63'              |
| Ref. 10   |                                   | 0.153                     | 0.103               |           | 27 <sup>đ</sup>                |
|   | As                                | 0.515                     | -0.257              | -148      | -159 / 304 / -145              |
| Ref. 10   |                                   | 0.694                     | -0.206              |           | 216 <sup>d</sup>               |
| $Ga_2As_3$ $D_{3h}$ , $X^2A_2$ "                                  | . Ga                              | 0.369                     | 0.194               | 1325°     | -65 / -65 / 129                |
| Ref. 9  |                                   | 0.314                     | 0.150               |           | . 81 <sup>d</sup>              |
| •   | As                                | 0.088                     | -0.129              | -23°      | -35 / -36 / 71                 |
| Ref. 9  | • • •                             | 0.124                     | -0.100              | •         | 14                             |
| $Ga_3As_2$ $C_{2v}$ , $X^2A_1$                                    | Ga <sub>1</sub>                   | 0.426                     | 0.175               | 1735      | -85 / -71 / 156                |
| •   | Ga <sub>2</sub> , Ga <sub>3</sub> | 0.085                     | 0.276               | 203       | -21 / 45' / -24'               |
|   | $As_1, As_2$                      | 0.202                     | -0.363              | -25       | -61' / -56 / 116'              |
| $GaAs_4 C_{2v}, X^2B_2$   | Ga                                | -0.038                    | 0.214               | -153      | . 4/17/-21                     |
|   | $As_1, As_2$                      | 0.585                     | -0.078              | -46       | -156 / 308' / -152'            |
|   | $As_3$ , $As_4$                   | -0.066                    | -0.030              | 12        | -10' / 45 / -36'               |
| $Ga_4As$ $C_{2v}$ , $X^2A_1$                                      | Ga <sub>1</sub> , Ga <sub>2</sub> | 0.342                     | 0.083               | -122      | -89 / 177' / -88'              |
|   | Ga <sub>3</sub> , Ga <sub>4</sub> | 0.169                     | 0.171               | 153       | -34 / -43' / 76'               |
|   | As                                | -0.021                    | -0.509              | 0.05      | 13 / -7 / 20                   |

a Atomic charges from a Mulliken population analysis.

b Off-diagonal spin-dipolar (anisotropic) coupling terms  $T'_{xx}$ ,  $T'_{yy}$ ,  $T'_{zz}$  are indicated by a 'after the value.

 $c~A_{\rm iso}$  = 1524 [1936] MHz,  $A_{\rm dip}$  = 87 [71] MHz from experimental ESR spectra for  $^{69}{\rm Ga_2As_3}$  [ $^{71}{\rm Ga_2As_3}$ ].  $^2~A_{\rm iso}$ 

<sup>= 2012</sup> Mhz,  $A_{dip} = 88$  Mhz for  $^{71}Ga_2^{75}As_3$  in ref. 12.

d The spin-dipolar contribution to heac from ref. 13, defined as the expectation value  $(3x^2 - r^2)/r^5$  averaged over the relativistic wave function.

Table 3. Excited state couplings for the four possible ground states in  $C_{2\nu}\,\text{symmetry}.$ 

|              |                         | Excited State C             | Coupling                    |
|--------------|-------------------------|-----------------------------|-----------------------------|
| Ground State | $\Delta g_{xx}$         | $\Delta \mathtt{g}_{yy}$    | $\Delta g_{zz}$             |
| $X^2A_i$     | $^{2}\mathrm{B}_{2}$    | $^{2}\mathrm{B_{i}}$ .      | <sup>2</sup> A <sub>2</sub> |
| $X^2A_2$     | $^{2}\mathrm{B}_{_{1}}$ | $^{2}\mathrm{B}_{2}$        | $^{2}$ A $_{1}$             |
| $X^2B_1$     | $^{2}A_{2}$             | $^{2}A_{1}$                 | $^{2}\mathrm{B}_{2}$        |
| $X^2B_2$     | $^{2}A_{i}$             | <sup>2</sup> A <sub>2</sub> | $^{2}\mathrm{B}_{_{1}}$     |

Table 4. Calculated g-tensor data ( $\Delta g$  in ppm) for  $Ga_xAs_y$  (x + y = 3, 5), and comparison with experimental and other theoretical results.

|  | $\Delta g_{xx}$     | $\Delta g_{yy}$ | $\Delta g_{zz}$ |   |
|--|---------------------|-----------------|-----------------|---|
| GaAs <sub>2</sub> (X <sup>2</sup> B <sub>2</sub> ) | 175300              | -175120         | -18280          |   |
| Ref. 13, calc.                                     | 95600               | -116500         |                 |   |
| $Ga_2As(X^2B_2)$                                   | -125950             | -24850          | 51030           |   |
| Ref. 13, calc.                                     | -188500             | 40100           |                 |   |
| $Ga_2As_3$ ( $X^2A_2$ " in $D_{3h}$ )              | -73410 <sup>a</sup> |                 | 6460            |   |
| Ref. 2, expt.                                      | -82300              | -               | ~ 0             | ~ |
| Ref. 12, calc.                                     | -148000             | -               | -16200          |   |
| $Ga_3As_2(X^2A_1)$                                 | -71590 ·            | -11150          | 13270           |   |
| $GaAs_4(X^2B_2)$                                   | -171030             | -7540           | -14720          |   |
| $Ga_4As(X^2A_1)$                                   | -123540             | -21850          | -43470          |   |

a Average of  $\Delta g_{xx}$  and  $\Delta g_{yy}$  from Table 7.

Table 5. Calculated values of  $\Delta E$ , SO, L and  $\Delta g$  (2<sup>nd</sup> order) for excited states having a large magnetic coupling with the ground state of GaAs<sub>2</sub> (X<sup>2</sup>B<sub>2</sub>), and <sup>2</sup>B<sub>2</sub> vertical excitation energies<sup>a</sup>.

| Component   | ΔE (eV) | SO (cm <sup>-1</sup> ) | L (au) | $\Delta g (ppm)^b$   |
|---|---------|------------------------|--------|----------------------|
| $\Delta g_{xx} (^2A_1)$   |         |                        |        |                      |
| $1^{2}A_{1} (4a_{1} \rightarrow 2b_{2}, S-1 \rightarrow S)^{c}$                       | 1.47    | 169.5                  | 1.096  | 64366                |
| $2^{2}A_{1} (3a_{1} \rightarrow 2b_{2}, S-3 \rightarrow S)$                           | 2.67    | 475.1                  | 1.105  | 99952                |
| $3^2A_1 (1b_1 - 1a_2, S-2 - L)$   | 2.89    | 165.1                  | 0.149  | 4333                 |
| $4^{2}A_{1}(2b_{2} - 5a_{1}, S - L+3)$  | 3.97    | 116.2                  | 0.784  | 11687                |
| $5^{2}A_{1} (1b_{1} \rightarrow 1a_{2}, S-2 \rightarrow L) [30\%]$                    | 4.24    | 69.2                   | -0.404 | -3357 <b>175300</b>  |
| $\Delta g_{yy} (^2A_2)$   |         |                        |        |                      |
| $1^2A_2 (2b_2 - 1a_2, S - L)$   | 1.26    | 476.4                  | -0.897 | -172824              |
| $2^{2}A_{2}$ (4a <sub>1</sub> $\rightarrow$ 2b <sub>1</sub> , S-1 $\rightarrow$ .L+1) | 3.19    | 98.4                   | 0.872  | 13686                |
| $3^2A_2$ (4a <sub>1</sub> $\rightarrow$ 2b <sub>1</sub> , S-1 $\rightarrow$ L+1)      | 3.90    | -86.1                  | 1.530  | -17199               |
| $4^{2}A_{2} (3a_{1}4a_{1} \rightarrow 2b_{2}1a_{2}, S-3+S-1 \rightarrow S+L)$         | 4.37    | 31.8                   | 0.034  | 128                  |
| $5^{2}A_{2} (4a_{1}^{2} \rightarrow 2b_{2}1a_{2}, S-1 \rightarrow S+L) [26\%]$        | 4.71    | 50.1                   | 0.130  | 708 <b>-175120</b>   |
| $\Delta g_{zz} (^2B_1)$   |         |                        | •      |                      |
| $1^{2}B_{1} (2b_{2} \rightarrow 2b_{1}, S \rightarrow L+1)$                           | 2.27    | -129.3                 | 0.657  | -19067               |
| $2^{2}B_{1} (1b_{1} \rightarrow 2b_{2}, S-2 \rightarrow S)$                           | 2.55    | 36.5                   | -0.042 | -307                 |
| $3^{2}B_{1}$ (4a <sub>1</sub> $\rightarrow$ 1a <sub>2</sub> , S-1 $\rightarrow$ L)    | 2.62    | 81.2                   | -0.033 | -526                 |
| $4^{2}B_{1} (4a_{1} \rightarrow 1a_{2}, S-1 \rightarrow L) [57\%]$                    | 3.13    | 250.8                  | -0.149 | -6072                |
| $5^{2}B_{1} (3a_{1} \rightarrow 1a_{2}, S-3 \rightarrow L)$                           | 3.61    | 348.0                  | 0.983  | 48315                |
| $6^{2}B_{1} (3a_{1} \rightarrow 1a_{2}, S-3 \rightarrow L)$                           | 3.89    | 190.9                  | -1.612 | -40264 <b>-18280</b> |

a The  $X^2B_2$  ground state is ...  $1b_2^21b_1^24a_1^22b_2^1$  (13 VE). Vertical excitation energies for  $2^2B_2$  to  $5^2B_2$  are 3.58, 4.25, 4.35, and 4.76 eV, respectively.

 $\boldsymbol{b}$  Total contribution for all calculated excited states in boldface.

c S = SOMO, L = LUMO.

Table 6.Calculated values of  $\Delta E$ , SO, L and  $\Delta g$  (2<sup>nd</sup> order) for excited states having a large magnetic coupling with the ground state of Ga<sub>2</sub>As (X<sup>2</sup>B<sub>2</sub>), and <sup>2</sup>B<sub>2</sub> vertical excitation energies<sup>a</sup>.

| Component  | ΔE (eV) | SO (cm <sup>-1</sup> ) | L (au) | $\Delta g (ppm)^b$   |
|--|---------|------------------------|--------|----------------------|
| $\Delta \mathbf{g}_{xx} (^2 \mathbf{A}_1)$   |         |                        |        |                      |
| $1^{2}A_{1} (3a_{1} \rightarrow 2b_{2}, S-1 \rightarrow S)^{c}$                            | 0.17    | 177.4                  | -0.069 | -36004               |
| $2^{2}A_{1} (2b_{2} \rightarrow 4a_{1}, S \rightarrow L) [58\%]$                           | 1.97    | 243.5                  | -1.019 | -64115               |
| $3^{2}A_{1}$ (1b <sub>1</sub> $\rightarrow$ 1a <sub>2</sub> , S-2 $\rightarrow$ L+1) [33%] | 2.72    | -60.7                  | 0.735  | -8368                |
| $4^{2}A_{1} (3a_{1}^{2} \rightarrow 2b_{2}4a_{1}, S-1 \rightarrow S + L)$                  | 2.90    | -204.4                 | 0.910  | -32678               |
| $5^{2}A_{1} (1b_{1} \rightarrow 1a_{2}, S-2 \rightarrow L+1)$                              | 3.38    | -30.86                 | 0.306  | -1424                |
| $6^{2}A_{1}$ (3a <sub>1</sub> - 3b <sub>2</sub> , S-1 - L+3) [39%]                         | 3.72    | 84.9                   | 1.271  | 14761 <b>-125950</b> |
| $\Delta \mathbf{g}_{yy} (^2 \mathbf{A}_2)$   |         |                        |        |                      |
| $1^{2}A_{2} (1b_{1} - 4a_{1}, S-2 - L)$  | 2.32    | 2.7                    | 0.154  | 91                   |
| $2^{2}A_{2} (2b_{2} \rightarrow 1a_{2}, S \rightarrow L+1)$                                | 2.57    | 156.8                  | -0.477 | -14834               |
| $3^{2}A_{2} (1b_{1} \rightarrow 4a_{1}, S-2 \rightarrow L)$                                | 2.78    | 41.9                   | 0.014  | 108                  |
| $4^{2}A_{2} (3a_{1} \rightarrow 2b_{1}, S-1 \rightarrow L+2) [39\%]$                       | 3.32    | 158.5                  | -0.784 | -19071               |
| $5^2A_2$ (3a <sub>1</sub> $\rightarrow$ 2b <sub>1</sub> , S-1 $\rightarrow$ L+2)           | 3.82    | 100.8                  | 0.737  | 9909 -24850          |
| $\Delta \mathbf{g}_{zz} (^2 \mathbf{B}_1)$   |         |                        |        |                      |
| $1^{2}B_{1} (1b_{1} - 2b_{2}, S-2 - S)$  | 0.33    | 254.7                  | 0.219  | 87664                |
| $2^{2}B_{1} (1b_{1}3a_{1} \rightarrow 2b_{2}4a_{1}, S-2+S-1 \rightarrow S+L)$              | 2.57    | -0.2                   | 0.140  | -4                   |
| $3^{2}B_{1} (3a_{1} \rightarrow 1a_{2}, S-1 \rightarrow L+2)$                              | 2.66    | 122.2                  | 0.904  | 21148                |
| $4^{2}B_{1} (1b_{1}3a_{1} \rightarrow 2b_{2}4a_{1}, S-2+S-1 \rightarrow S+L)$              | 3.01    | 41.3                   | 0.051  | 360                  |
| $5^{2}B_{1} (3a_{1} \rightarrow 1a_{2}, S-1 \rightarrow L+2)$                              | 3.32    | -220.1                 | 1.066  | -35932               |
| $6^{2}B_{1} (2b_{2} - 2b_{1}, S - L+2) [40\%]$   | 3.74    | 146.9                  | -1.052 | -21056 51030         |

a The  $X^2B_2$  ground state is ...  $1b_2^21b_1^23a_1^22b_2^1$  (11 VE). Vertical excitation energies for  $2^2B_2$  to  $5^2B_2$  are 2.24,

2.65, 3.17, and 3.41 eV, respectively.

b Total contribution for all calculated excited states in boldface.

c S = SOMO, L = LUMO.

Table 7. Calculated values of  $\Delta E$ , SO, L and  $\Delta g$  (2<sup>nd</sup> order) for excited states having a large magnetic coupling with the ground state of  $Ga_2As_3$  ( $X^2B_1$ ), and  $^2B_1$  vertical excitation energies<sup>a</sup>.

| Component  | ΔE (eV) | SO (cm <sup>-1</sup> ) | L (au) | $\Delta g (ppm)^b$  |
|--|---------|------------------------|--------|---------------------|
| $\Delta g_{xx} (^2A_1)$  |         |                        |        |                     |
| $1^2A_1 (5a_1 + 3b_1, S-3 + S)^c$  | 1.98    | 41.5                   | -0.037 | -398                |
| $2^{2}A_{1}$ (4a <sub>1</sub> $\rightarrow$ 3b <sub>1</sub> , S-5 $\rightarrow$ S)   | 2.98    | 0.4                    | -0.014 | -1                  |
| $3^2A_1$ $(3b_1 \rightarrow 6a_1, S \rightarrow L)$                                  | 3.30    | 342.9                  | -1.777 | -94074              |
| $4^2A_1 (3a_1 - 3b_1, S-6 - S)$  | 3.87    | 0.02                   | 0.003  | 0                   |
| $5^2A_1 (3b_1 \rightarrow 7a_1, S \rightarrow L+4)$                                  | 3.70    | 246.7                  | 0.634  | 21549               |
| $6^2A_1$ (1a <sub>2</sub> - 4b <sub>2</sub> , S-2 - L+2)                             | 3.43    | 148.1                  | 0.396  | 8742                |
| $7^{2}A_{1}$ (1a <sub>2</sub> $\rightarrow$ 4b <sub>2</sub> , S-2 $\rightarrow$ L+2) | 2.29    | 133.4                  | -0.368 | -10911 -75230       |
| $\Delta g_{yy} (^2B_2)$  |         |                        |        |                     |
| $1^{2}B_{2} (2b_{2} - 3b_{1}, S-4 - S)$  | 2.69    | -40.5                  | 0.037  | -284                |
| $2^{2}B_{2} (3b_{1} \rightarrow 3b_{2}, S \rightarrow L+1)$                          | 3.28    | -355.5                 | 1.761  | -97100              |
| $3^{2}B_{2} (3b_{1} \rightarrow 4b_{2}, S \rightarrow L+2)$                          | 3.50    | 4.9                    | 0.032  | 23                  |
| $4^{2}B_{2} (3b_{1} \rightarrow 5b_{2}, S \rightarrow L+3)$                          | 3.67    | 269.0                  | 0.713  | 26635               |
| $5^{2}B_{2} (2b_{1} \rightarrow 4b_{2}, S-1 \rightarrow L+2)$                        | 3.83    | 101.8                  | 0.316  | 4287                |
| $6^{2}B_{2} (2b_{1} \rightarrow 4b_{2}, S-1 \rightarrow L+2)$                        | 3.93    | 119.2                  | -0.342 | -5280 <b>-71590</b> |
|  |         |                        |        |                     |

| $\Delta g_{zz} (^2A_2)$  |      |       |                    |      |      |
|--|------|-------|--------------------|------|------|
| $1^2A_2 (1a_2 \rightarrow 3b_1, S-2 \rightarrow S)$                              | 1.58 | -0.1  | 3x10 <sup>-4</sup> | 0    |      |
| $2^{2}A_{2}$ (5a <sub>1</sub> - 4b <sub>2</sub> , S-3 - L+2)                     | 3.64 | 0.9   | 6x10 <sup>-5</sup> | 0    |      |
| $3^2A_2$ (4a <sub>1</sub> $\rightarrow$ 4b <sub>2</sub> , S-5 $\rightarrow$ L+2) | 2.89 | 71.8  | 0.401              | 5083 |      |
| $4^{2}A_{2}$ (3b <sub>1</sub> - 2a <sub>2</sub> , S - L+7)                       | 4.55 | 0.3   | 2x10 <sup>-4</sup> | 0    |      |
| $5^2A_2$ (5a <sub>1</sub> - 4b <sub>2</sub> , S-3 - L+2)                         | 3.85 | 0.7   | -0.021             | -2   |      |
| $6^{2}A_{2}$ (5a <sub>1</sub> - 5b <sub>2</sub> , S-3 - L+3) [50%]               | 4.09 | 194.5 | 0.084              | 2041 | 6460 |

a The  $X^2B_2$  ground state is ... $2b_2^25a_1^21a_2^22b_1^23b_1^1$  (21 VE). Vertical excitation energies for  $2^2B_1$  to  $5^2B_1$  are 1.58, 3.85, 4.54, and 4.50 eV, respectively.

b Total contribution for all calculated excited states in boldface.

c S = SOMO, L = LUMO.

Table 8. Calculated values of  $\Delta E$ , SO, L and  $\Delta g$  (2<sup>nd</sup> order) for excited states having a large magnetic coupling with the ground state of  $Ga_3As_2$  ( $X^2A_1$ ), and  $^2A_1$  vertical excitation energies<sup>a</sup>.

| Component   | ΔE (eV) | SO (cm <sup>-1</sup> ) | L (au) | $\Delta g (ppm)^b$  |
|---|---------|------------------------|--------|---------------------|
| $\Delta g_{xx} (^2B_2)$   |         |                        |        |                     |
| $1^{2}B_{2} (2b_{2} \rightarrow 5a_{1}, S-1 \rightarrow S)^{c}$       | 0.72    | -72.2                  | 0.525  | -26906              |
| $2^{2}B_{2} (1a_{2} \rightarrow 3b_{1}, S-2 \rightarrow L+2)$         | 1.87    | 5.1                    | 0.038  | 53                  |
| $3^{2}B_{2} (5a_{1} \rightarrow 3b_{2}, S \rightarrow L) [48\%]$      | 2.94    | 221.4                  | -1.402 | -53718              |
| $4^{2}B_{2} (1a_{2} - 3b_{1}, S-2 - L+2)$                             | 2.52    | 46.7                   | -0.653 | -6177               |
| $5^{2}B_{2} (2b_{2} \rightarrow 6a_{1}, S-1 \rightarrow L+1) [52\%]$  | 2.94    | 22.2                   | -0.921 | -3537               |
| $6^2B_2 (2b_2 - 6a_1, S-1 - L+1)$                                     | 3.16    | 72.1                   | 1.605  | 18664 <b>-71590</b> |
| $\Delta g_{yy} (^2B_1)$   |         |                        |        |                     |
| $1^{2}B_{1} (2b_{1} \rightarrow 5a_{1}, S-3 \rightarrow S)$           | 1.15    | 80.3                   | 0.902  | 32076               |
| $2^{2}B_{1} (1a_{2} \rightarrow 3b_{2}, S-2 \rightarrow L)$           | 2.52    | 41.2                   | -0.783 | -6518               |
| $3^{2}B_{1} (5a_{1} \rightarrow 3b_{1}, S \rightarrow L+2)$           | 2.94    | 320.5                  | -0.599 | -33328              |
| $4^{2}B_{1} (1a_{2} \rightarrow 3b_{2}, S-2 \rightarrow L)$           | 2.58    | 15.3                   | -0.506 | -1530               |
| $5^2B_1 (2b_1 \rightarrow 6a_1, S-3 \rightarrow L+1)$                 | 3.90    | 24.8                   | 0.567  | 1840                |
| $6^2B_1$ (4a <sub>1</sub> - 3b <sub>1</sub> , S-4 - L+2)              | 2.50    | -79.7                  | 0.511  | -8297               |
| $11^2B_1 (5a_1 \rightarrow 4b_1, S \rightarrow L+3)$                  | 4.34    | 71.2                   | 0.955  | 7981                |
| $14^{2}B_{1} (3a_{1} \rightarrow 3b_{1}, S-5 \rightarrow L+2) [26\%]$ | 4.20    | 73.5                   | -0.732 | -6536 <b>-11150</b> |

| $\Delta g_{zz}$ | $^{2}A_{2}$ |
|-----------------|-------------|
|-----------------|-------------|

| $5^2A_2$ (1a <sub>2</sub> $\rightarrow$ 6a <sub>1</sub> , S-2 $\rightarrow$ L+1) | 2.92 | 2.7   | -0.415 | -200   | 13270 |
|--|------|-------|--------|--------|-------|
| $4^{2}A_{2} (1a_{2} \rightarrow 6a_{1}, S-2 \rightarrow L+1)$                    | 3.05 | 20.8  | 0.630  | 2191   |       |
| $3^{2}A_{2} (2b_{2} \rightarrow 3b_{1}, S-1 \rightarrow L+2)$                    | 2.79 | 75.3  | -1.121 | -15409 |       |
| $2^{2}A_{2} (2b_{2} - 3b_{1}, S-1 - L+2)$  | 2.73 | 253.8 | 0.252  | 11927  |       |
| $1^2A_2 (1a_2 - 5a_1, S-2 - S)$  | 1.00 | 76.5  | 0.394  | 15339  |       |
|  |      |       |        |        |       |

a The  $X^2A_1$  ground state is ... $4a^{12}2b_1^21a_2^22b_2^25a_1^1$  (19 VE). Vertical excitation energies for  $2^2A_1$  to  $5^2A_1$  are 1.68, 2.18, 2.56, and 2.90 eV, respectively.

$$c$$
 S = SOMO, L = LUMO.

b Total contribution for all calculated excited states in boldface.

Table 9. Calculated values of  $\Delta E$ , SO, L and  $\Delta g$  (2<sup>nd</sup> order) for excited states having a large magnetic coupling with the ground state of GaAs<sub>4</sub> (X<sup>2</sup>B<sub>2</sub>), and <sup>2</sup>B<sub>2</sub> vertical excitation energies.

| Component   |      | SO                  | L (au) | $\Delta g (ppm)^b$   |
|---|------|---------------------|--------|----------------------|
|   | (eV) | (cm <sup>-1</sup> ) |        |                      |
| $\Delta g_{xx}(A_1)$  |      |                     |        |                      |
| $1^{2}A_{1} (3b_{2} \rightarrow 6a_{1}, S \rightarrow L)^{c}$                         | 0.55 | 390.3               | -0.496 | -179018              |
| $2^{2}A_{1} (5a_{1} \rightarrow 3b_{2}, S-1 \rightarrow S)$                           | 2.22 | -249.0              | 1.0471 | -59761               |
| $3^2A_1 (3b_2 - 7a_1, S - L+4)$   | 2.46 | 171.5               | 0.070  | 2501                 |
| $4^{2}A_{1} (2b_{2} \rightarrow 6a_{1}, S-3 \rightarrow L)$                           | 2.82 | 265.0               | 0.7923 | 37977                |
| $5^{2}A_{1} (2b_{2} \rightarrow 6a_{1}, S-3 \rightarrow L) [64\%]$                    | 2.61 | -139.8              | 0.386  | -10558               |
| $9^{2}A_{1} (5a_{1} \rightarrow 4b_{2}, S \rightarrow L+1) [39\%]$                    | 4.10 | 162.8               | 1.850  | 37462 <b>-171030</b> |
| $\Delta \mathbf{g}_{yy} (^2 \mathbf{A}_2)$  |      |                     |        |                      |
| $1^2A_2 (3b_1 \rightarrow 6a_1, S-2 \rightarrow L)$                                   | 1.91 | -311.7              | 0.807  | -66989               |
| $2^{2}A_{2} (3b_{1} \rightarrow 6a_{1}, S-2 \rightarrow L)$                           | 2.32 | 162.1               | 1.378  | 49104                |
| $3^2A_2 (3b_2 - 2a_2, S - L+5)$   | 3.06 | -188.6              | 0.117  | -3699                |
| $4^2A_2 (2b_1 \rightarrow 6a_1, S-4 \rightarrow L)$                                   | 3.37 | 336.6               | 0.057  | -2937                |
| $5^2A_2 (2b_1 \rightarrow 6a_1, S-4 \rightarrow L)$                                   | 3.18 | 129.2               | 0.794  | 16423                |
| $6^2A_2$ (5a <sub>1</sub> - 4b <sub>1</sub> , S-1 - L+3)                              | 2.91 | 123.4               | -0.372 | -8027                |
| $7^2A_2 (3b_1 \rightarrow 7a_1, S-2 \rightarrow L+4)$                                 | 3.44 | 111.3               | -0.321 | -5292                |
| $9^2A_2 (1a_2 \rightarrow 3b_2, S-5 \rightarrow S)$                                   | 3.78 | 49.5                | -0.355 | -2363                |
| $10^2 A_2 (3b_1 \rightarrow 7a_1, S-2 \rightarrow L+4)$                               | 4.43 | 83.0                | 1.561  | 14898                |
| $11^2 A_2 (5a_1 - 4b_1, S-1 - L+3) [55\%]$  | 3.67 | 84.2                | -0.494 | -5790                |
| $13^{2}A_{2} (3b_{1}3b_{2} \rightarrow 6a_{1}5b_{2}, S-2+S \rightarrow L+L+2) [28\%]$ | 3.66 | 70.5                | 0.702  | 6890 <b>-7540</b>    |

| $\Delta g_{zz} (^2B_1)$   |      |        |       |        |        |
|---|------|--------|-------|--------|--------|
| $1^{2}B_{1} (3b_{1} - 3b_{2}, S-2 - S)$                                   | 1.90 | 285.7  | 0.777 | 59501  |        |
| $2^{2}B_{1} (3b_{2} \rightarrow 4b_{1}, S \rightarrow L+3)$               | 2.57 | -259.9 | 1.285 | -66074 |        |
| $3^{2}B_{1} (3b_{1}3b_{2} \rightarrow 6a_{1}^{2}, S-2 + S \rightarrow L)$ | 2.40 | 163.7  | 0.200 | 6966   |        |
| $4^{2}B_{1} (2b_{1} \rightarrow 3b_{2}, S-4 \rightarrow L)$               | 3.10 | 293.5  | 0.102 | 4943   |        |
| $5^{2}B_{1} (3b_{1} \rightarrow 4b_{2}, S-2 \rightarrow L+1)$             | 3.19 | -63.2  | 0.765 | -7720  |        |
| $6^{2}B_{1} (3b_{2} \rightarrow 5b_{1}, S \rightarrow L+6) [58\%]$        | 2.54 | -79.2  | 0.921 | -14645 |        |
| $8^{2}B_{1}$ (3b <sub>1</sub> - 5b <sub>2</sub> , S-2 - L+2)              | 3.67 | -118.9 | 1.378 | -22751 |        |
| $11^2B_1 (3b_1 - 5b_2, S-2 - L+2)$  | 3.72 | 114.4  | 1.319 | 20686  | -14720 |

a The  $X^2B_2$  ground state is ... $1a_2^22b_2^23b_1^25a_1^23b_2^1$  (23 VE). Vertical excitation energies for  $2^2B_2$  to  $5^2B_2$  are 1.62, 2.60, 2.54, and 2.63 eV, respectively.

b Total contribution for all calculated excited states in boldface.

c S = SOMO, L = LUMO.

Table 10. Calculated values of  $\Delta E$ , SO, L and  $\Delta g$  (2<sup>nd</sup> order) for excited states having a large magnetic coupling with the ground state of Ga<sub>4</sub>As (X<sup>2</sup>A<sub>1</sub>), and <sup>2</sup>A<sub>1</sub> vertical excitation energies<sup>a</sup>.

| Component  | ΔΕ   | SO                  | L (au) | Δg (ppm) | ь       |
|--|------|---------------------|--------|----------|---------|
|  | (eV) | (cm <sup>-1</sup> ) |        |          |         |
| $\Delta g_{xx} (^2B_2)$  |      |                     |        |          |         |
| $1^{2}B_{2} (5a_{1} \rightarrow 4b_{2}, S \rightarrow L+1)^{c} [62\%]$               | 1.28 | 223.4               | -1.224 | -108538  |         |
| $2^{2}B_{2}$ (5a <sub>1</sub> - 4b <sub>2</sub> , S - L+1) [29%]                     | 1.59 | -51.6               | 1.4029 | -23187   |         |
| $3^{2}B_{2} (2b_{2} - 5a_{1}, S-4 - S)$  | 2.73 | -24.1               | 1.423  | -6406    |         |
| $4^{2}B_{2} (1b_{1} \rightarrow 1a_{2}, S-3 \rightarrow L)$                          | 2.98 | 6.6                 | -0.664 | -751     |         |
| $5^{2}B_{2} (1b_{1} \rightarrow 1a_{2}, S-3 \rightarrow L) [46\%]$                   | 3.02 | -23.0               | -0.147 | 572      | -123540 |
| $\Delta g_{yy} (^2B_1)$  |      |                     |        |          |         |
| $1^{2}B_{1} (5a_{1} \rightarrow 2b_{1}, S \rightarrow L+2)$                          | 1.45 | -18.1               | 0.216  | -1378    |         |
| $2^{2}B_{1} (1b_{1} \rightarrow 5a_{1}, S-3 \rightarrow S)$                          | 2.23 | 47.8                | -0.041 | -457     |         |
| $3^{2}B_{1}(3b_{2} \rightarrow 1a_{2}, S-1 \rightarrow L)$                           | 2.03 | -1.6                | 0.148  | -61      |         |
| $4^{2}B_{1} (3b_{2} \rightarrow 1a_{2}, S-1 \rightarrow L)$                          | 2.44 | -30.0               | 0.224  | -1405    |         |
| $5^{2}B_{1}$ (4a <sub>1</sub> $\rightarrow$ 2b <sub>1</sub> , S-2 $\rightarrow$ L+2) | 2.75 | 249.0               | 0.0782 | 3601     |         |
| $6^{2}B_{1} (4a_{1} \rightarrow 2b_{1}, S-2 \rightarrow L+2)$                        | 2.92 | -30.7               | 1.616  | -8668    |         |
| $7^{2}B_{1} (5a_{1} \rightarrow 3b_{1}, S \rightarrow L+3)$                          | 3.06 | -72.1               | 0.724  | -8675    |         |
| $8^{2}B_{1} (2b_{2} \rightarrow 1a_{2}, S-4 \rightarrow L)$                          | 2.99 | -24.6               | 1.409  | -5893    | -21850  |

| $12^{2}A_{2} (3b_{2} \rightarrow 3b_{1}, S-1 \rightarrow L+3) [60\%]$<br>$14^{2}A_{2} (2b_{2} \rightarrow 2b_{1}, S-4 \rightarrow L+2)$ | 3.96<br>3.98 | -63.9<br>-39.4 | 1.277<br>1.652 | -10487<br>-8334 | -43470 |
|---|--------------|----------------|----------------|-----------------|--------|
| $11^{2}A_{2} (3b_{2} \rightarrow 3b_{1}, S-1 \rightarrow L+3) [42\%]$   | 3.83         | 102.7          | 0.847          | 11592           |        |
| $7^{2}A_{2} (5a_{1} \rightarrow 2a_{2}, S \rightarrow L+5) [41\%]$  | 3.26         | 205.7          | -0.451         | -14511          |        |
| $6^2A_2$ (3b <sub>2</sub> - 2b <sub>1</sub> , S-1 - L+2)  | 3.44         | 215.6          | -0.422         | -13477          |        |
| $5^2A_2$ (1b <sub>1</sub> $\rightarrow$ 4b <sub>2</sub> , S-3 $\rightarrow$ L+1)  | 2.93         | 7.1            | -0.049         | -62             |        |
| $4^2A_2$ (3b <sub>2</sub> - 2b <sub>1</sub> , S-1 - L+2)  | 2.42         | -43.5          | -0.432         | 3948            |        |
| $3^2A_2$ ( $4a_1 \rightarrow 1a_2$ , S-2 $\rightarrow$ L)   | 2.62         | 12.7           | -0.105         | -262            |        |
| $2^{2}A_{2}$ (4a <sub>1</sub> $\rightarrow$ 1a <sub>2</sub> , S-2 $\rightarrow$ L)  | 2.49         | -0.06          | 0.357          | <b>-</b> 5      |        |
| $1^2A_2 (5a_1 \rightarrow 1a_2, S \rightarrow L)$   | 1.22         | -63.9          | 0.256          | -6838           |        |
| $\Delta g_{zz} (^2A_2)$   |              |                |                |                 |        |

a The  $X^2A_1$  ground state is ...1 $b_1^24a_1^23b_2^25a_1^1$  (17 VE). Vertical excitation energies for  $2^2A_1$  to  $5^2A_1$  are 1.66, 2.79, 2.80, and 3.02 eV, respectively.

b Total contribution for all calculated excited states in boldface.

c S = SOMO, L = LUMO.

## Captions for figures:

Figure 1. Optimized geometries of  $Ga_xAs_y$  (x + y = 3, 5) isomers, shown in increasing relative energy from left to right. Bond lengths and angles given in Table 1.

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